

# **CET** 中电国基南方集团有限公司

# WS3A008120A

## Silicon Carbide Schottky Diode

V <sub>RRM</sub>	=	1200	V
I <sub>F</sub> ( T <sub>C</sub> ≤135°C)	=	12	Α
$\mathbf{Q}_{C}$	=	23	nC

#### **Features**

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V<sub>F</sub>
- Temperature-independent Switching
- 175°C Operating Junction Temperature

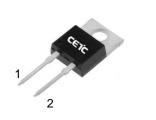
#### **Benefits**

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

## **Applications**

- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

## **Package**





TO-220-2



Part Number	Package	Marking
WS3A008120A	TO-220-2	WS3A008120A

## **Maximum Ratings**

Symbol	Parameter	Value	Unit	Test Conditions	Note
$V_{RRM}$	Repetitive Peak Reverse Voltage	1200	V	T <sub>C</sub> = 25°C	
$V_{RSM}$	Surge Peak Reverse Voltage	1200	V	T <sub>C</sub> = 25°C	
$V_R$	DC Blocking Voltage	1200	V	T <sub>C</sub> = 25°C	
I <sub>F</sub>	Forward Current	24.5 12 8	А	T <sub>C</sub> ≤ 25°C T <sub>C</sub> ≤ 135°C T <sub>C</sub> ≤ 156°C	
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current	80	Α	$T_C = 25^{\circ}C$ , $t_p = 8.3$ ms, Half Sine Wave	
P <sub>tot</sub>	Power Dissipation	150	W	T <sub>C</sub> = 25°C	Fig.3
Tc	Maximum Case Temperature	156	°C		
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperature	-55 to 175	°C		
	TO-220 Mounting Torque	1	Nm	M3 Screw	



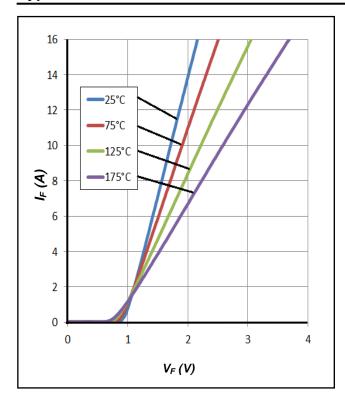
#### **Electrical Characteristics**

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note	
V <sub>F</sub>	Forward Voltage	1.55	1.8	V	I <sub>F</sub> = 8A, T <sub>J</sub> = 25°C	F: ~ 4	
		2.2 2.5 V I	I <sub>F</sub> = 8A, T <sub>J</sub> = 175°C	Fig.1			
I <sub>R</sub>	Reverse Current	1	20		V <sub>R</sub> = 1200V, T <sub>J</sub> = 25°C	F: 0	
		8	100	μA	V <sub>R</sub> = 1200V, T <sub>J</sub> = 175°C	Fig.2	
		520			$V_R = 0V, T_J = 25^{\circ}C, f = 1MHz$		
С	Total Capacitance	38	/	pF	$V_R = 400V, T_J = 25^{\circ}C, f = 1MHz$	Fig.5	
		30	30			$V_R = 800V, T_J = 25^{\circ}C, f = 1MHz$	
Qc	Total Capacitive Charge		/		$V_R = 800V, I_F = 8A$	F: 4	
		Total Capacitive Charge 23		nC	di/dt = 200A/µs, T <sub>J</sub> = 25°C	Fig.4	

### **Thermal Characteristics**

Symbol	Parameter	Тур.	Unit	Note
R <sub>θJC</sub>	Thermal Resistance from Junction to Case	1	°C/W	Fig.6
$R_{\theta JA}$	BJA Thermal Resistance from Junction to Ambient		°C/W	
T <sub>sold</sub> Soldering Temperature		260	°C	

## **Typical Performance**



80

(Va)

40

25°C

75°C

125°C

175°C

175°C

175°C

175°C

175°C

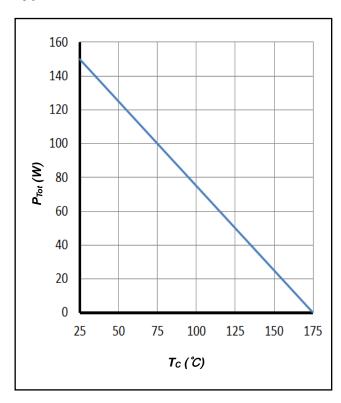
175°C

Figure 1. Forward Characteristics

Figure 2. Reverse Characteristics

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## **Typical Performance**



25 20 15 0 0 0 300 600 900 1200 V<sub>R</sub> (V)

Figure 3. Power Derating

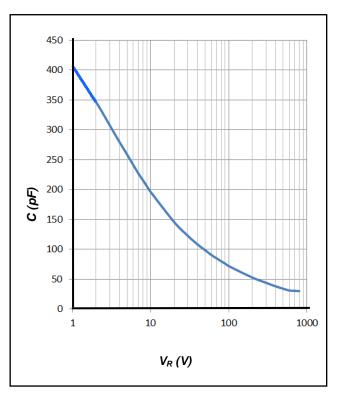


Figure 5. Total Capacitance vs. Reverse Voltage

Figure 4. Total Capacitive Charge vs. Reverse Voltage

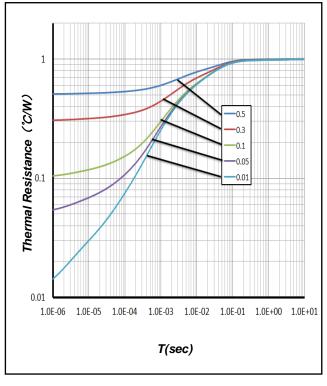
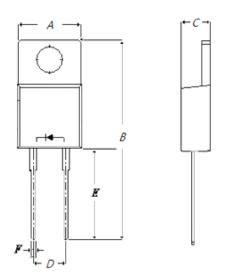


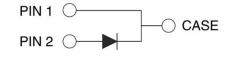
Figure 6. Transient Thermal Impedance



## **Package Dimensions**

Package TO-220-2

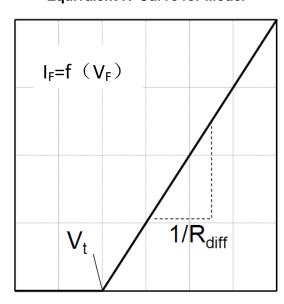




Symbol	Min. (mm)	Typ. (mm)	Max. (mm)
А	9.17	10.08	10.91
В	27.00	28.58	30.00
С	3.89	4.50	5.00
D	4.20	5.10	5.80
E	11.70	13.30	14.97
F	0.50	0.80	1.21

## **Simplified Diode Model**

### **Equivalent IV Curve for Model**



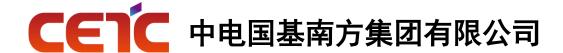
### **Mathematical Equation**

$$V_F = V_t + I_F \times R_{diff}$$

$$\begin{split} V_t &= -0.0025 \textbf{x} T_j + 0.99 \ [V] \\ R_{diff} &= 1.73 \textbf{x} 10^{-6} \textbf{x} T_j^2 + 3.64 \textbf{x} 10^{-4} \textbf{x} T_j + 0.066 \ [\Omega] \end{split}$$

#### Note:

 $Tj = \mbox{Diode Junction Temperature In Degrees Celsius,} \\ \mbox{valid from } 25^{\circ}\mbox{C to } 175^{\circ}\mbox{C} \\ \mbox{I}_{\text{F}} = \mbox{Forward Current} \\ \mbox{Less than } 16\mbox{A} \\ \mbox{}$ 



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